

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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# HN58W241000I

Two-wire serial interface  
1M EEPROM (128-kword  $\times$  8-bit)

REJ03C0138-0300

Rev.3.00

Jul.12.2005

## Description

HN58W241000I is the two-wire serial interface EEPROM (Electrically Erasable and Programmable ROM). It realizes high speed, low power consumption and a high level of reliability by employing advanced MNOS memory technology and CMOS process and low voltage circuitry technology. It also has a 256-byte page programming function to make it's write operation faster.

Note: Renesas Technology's serial EEPROM are authorized for using consumer applications such as cellular phone, camcorders, audio equipment. Therefore, please contact Renesas Technology's sales office before using industrial applications such as automotive systems, embedded controllers, and meters.

## Features

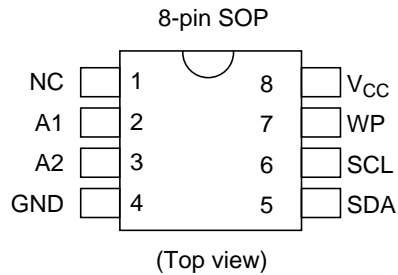
- Single supply: 2.5 V to 3.6 V
- Two-wire serial interface (I<sup>2</sup>C<sup>TM</sup> serial bus\*<sup>1</sup>)
- Clock frequency: 1 MHz
- Power dissipation:
  - Standby: 1  $\mu$ A (max)
  - Active (Read): 1 mA (max)
  - Active (Write): 4 mA (max)
- Automatic page write: 256-byte/page
- Write cycle time: 5.0 ms (max)
- Endurance: 10<sup>5</sup> Cycles
- Data retention: 10 Years
- Small size packages: SOP-8pin (200 mil-wide)
- Shipping tape and reel: 1,500 IC/reel
- Temperature range: -40 to +85°C
- Lead free products.

Note: 1. I<sup>2</sup>C is a trademark of Philips Corporation.

## Ordering Information

Type No.	Internal organization	Operating voltage	Frequency	Package
HN58W241000FPIE	1M bit (131,072 $\times$ 8-bit)	2.5 V to 3.6 V	1 MHz	200 mil 8-pin plastic SOP PRSP0008DG-B (FP-8DFV) Lead free

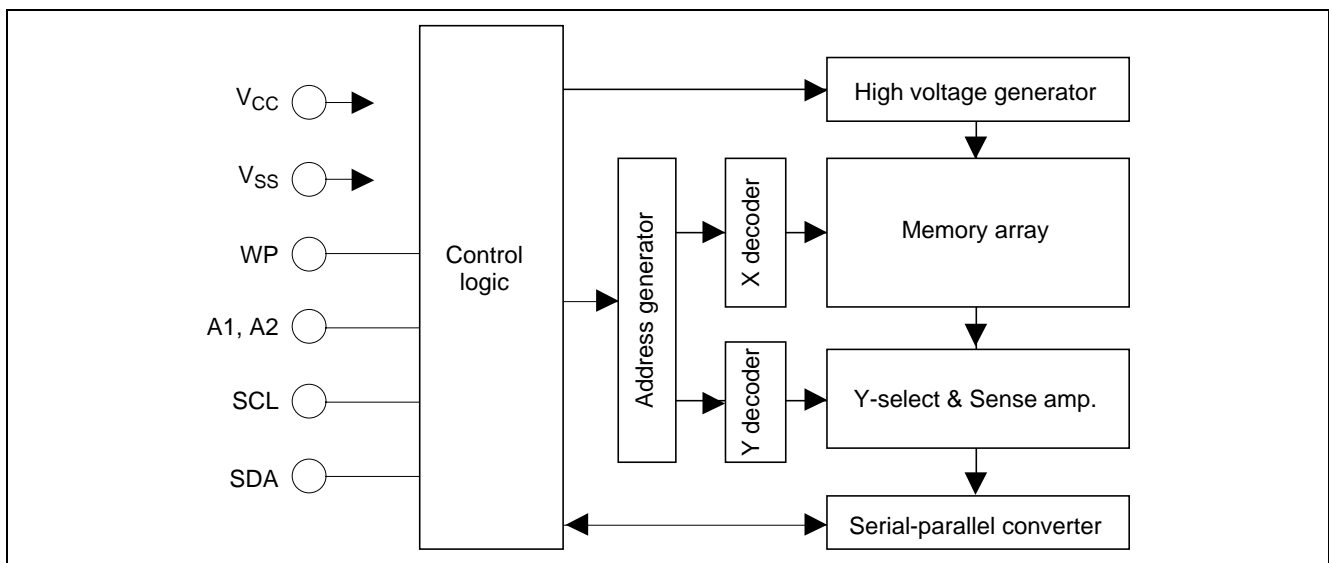
## Pin Arrangement



## Pin Description

Pin name	Function
A1, A2	Device address
SCL	Serial clock input
SDA	Serial data input/output
WP	Write protect
V <sub>CC</sub>	Power supply
V <sub>SS</sub>	Ground
NC	No connection

## Block Diagram



## Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply voltage relative to V <sub>SS</sub>	V <sub>CC</sub>	-0.6 to +7.0	V
Input voltage relative to V <sub>SS</sub>	V <sub>in</sub>	-0.5* <sup>2</sup> to +7.0* <sup>3</sup>	V
Operating temperature range* <sup>1</sup>	T <sub>opr</sub>	-40 to +85	°C
Storage temperature range	T <sub>stg</sub>	-65 to +125	°C

Notes: 1. Including electrical characteristics and data retention.

2. V<sub>in</sub> (min): -3.0 V for pulse width ≤ 50 ns.

3. Should not exceed V<sub>CC</sub> + 1.0 V.

## DC Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	$V_{CC}$	2.5	—	3.6	V
	$V_{SS}$	0	0	0	V
Input high voltage	$V_{IH}$	$V_{CC} \times 0.7$	—	$V_{CC} + 0.5^{*2}$	V
Input low voltage	$V_{IL}$	$-0.3^{*1}$	—	$V_{CC} \times 0.3$	V
Operating temperature	$T_{opr}$	-40	—	+85	°C

Notes: 1.  $V_{IL}$  (min): -1.0 V for pulse width  $\leq 50$  ns.

2.  $V_{IH}$  (max):  $V_{CC} + 1.0$  V for pulse width  $\leq 50$  ns.

## DC Characteristics (Ta = -40 to +85°C, $V_{CC}$ = 2.5 V to 3.6 V)

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Input leakage current	$I_{LI}$	—	—	2.0	$\mu A$	$V_{CC} = 3.6$ V, $V_{in} = 0$ to 3.6 V (SCL, SDA)
		—	—	20	$\mu A$	$V_{CC} = 3.6$ V, $V_{in} = 0$ to 3.6 V (A1, A2, WP)
Output leakage current	$I_{LO}$	—	—	2.0	$\mu A$	$V_{CC} = 3.6$ V, $V_{out} = 0$ to 3.6 V
Standby $V_{CC}$ current	$I_{SB}$	—	—	1.0	$\mu A$	$V_{in} = V_{SS}$ or $V_{CC}$
Read $V_{CC}$ current	$I_{CC1}$	—	—	1.0	mA	$V_{CC} = 3.6$ V, Read at 1 MHz
Write $V_{CC}$ current	$I_{CC2}$	—	—	4.0	mA	$V_{CC} = 3.6$ V, Write at 1 MHz
Output low voltage	$V_{OL}$	—	—	0.4	V	$V_{CC} = 2.5$ to 3.6 V, $I_{OL} = 0.8$ mA

## Capacitance (Ta = +25°C, f = 1 MHz)

Parameter	Symbol	Min	Typ	Max	Unit	Test conditions
Input capacitance (A1 to A2, SCL, WP)	$C_{in}^{*1}$	—	—	6.0	pF	$V_{in} = 0$ V
Output capacitance (SDA)	$C_{IO}^{*1}$	—	—	6.0	pF	$V_{out} = 0$ V

Note: 1. This parameter is sampled and not 100% tested.

**AC Characteristics** ( $T_a = -40$  to  $+85^{\circ}\text{C}$ ,  $V_{CC} = 2.5$  to  $3.6\text{ V}$ )**Test Conditions**

- Input pules levels:
  - $V_{IL} = 0.2 \times V_{CC}$
  - $V_{IH} = 0.8 \times V_{CC}$
- Input rise and fall time:  $\leq 20\text{ ns}$
- Input and output timing reference levels:  $0.5 \times V_{CC}$
- Output load: TTL Gate +  $100\text{ pF}$

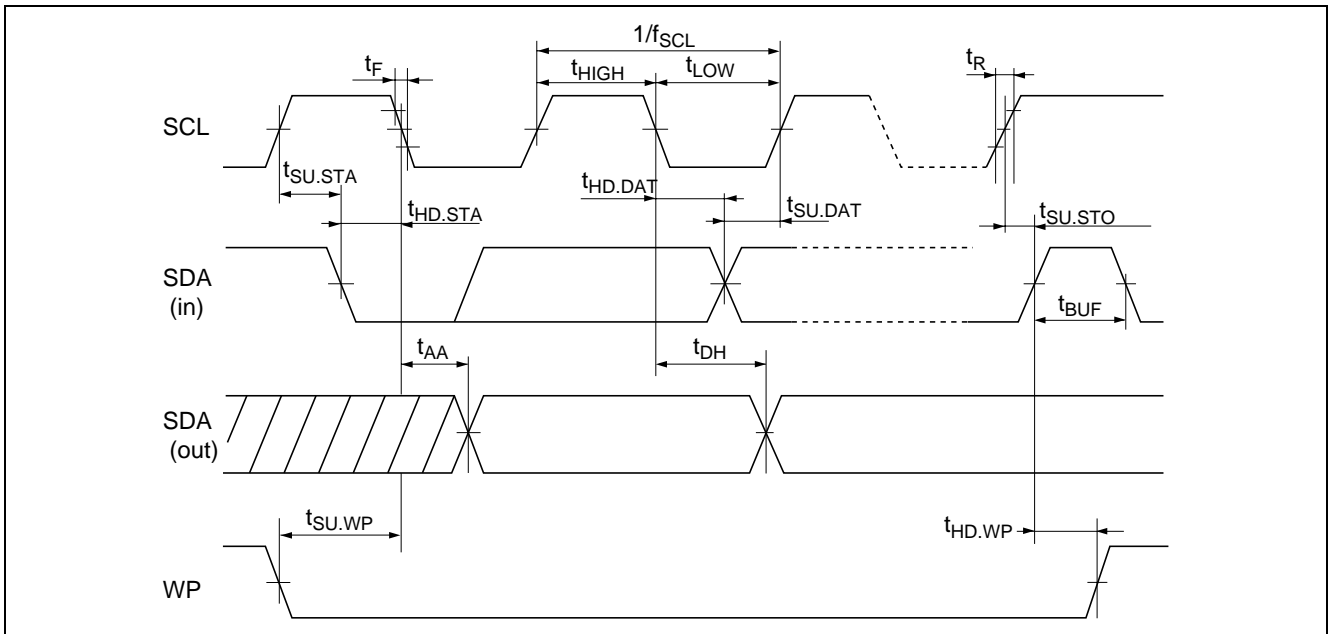
Parameter	Symbol	$V_{CC} = 2.5\text{ to }3.6\text{ V}$			Unit	Notes
		Min	Typ	Max		
Clock frequency	$f_{SCL}$	—	—	1000	kHz	
Clock pulse width low	$t_{LOW}$	600	—	—	ns	
Clock pulse width high	$t_{HIGH}$	400	—	—	ns	
Noise suppression time	$t_I$	—	—	50	ns	1
Access time	$t_{AA}$	100	—	550	ns	
Bus free time for next mode	$t_{BUF}$	500	—	—	ns	
Start hold time	$t_{HD.STA}$	250	—	—	ns	
Start setup time	$t_{SU.STA}$	250	—	—	ns	
Data in hold time	$t_{HD.DAT}$	0	—	—	ns	
Data in setup time	$t_{SU.DAT}$	100	—	—	ns	
Input rise time	$t_R$	—	—	300	ns	1
Input fall time	$t_F$	—	—	100	ns	1
Stop setup time	$t_{SU.STO}$	250	—	—	ns	
Data out hold time	$t_{DH}$	50	—	—	ns	
Write protect hold time	$t_{HD.WP}$	1000	—	—	ns	
Write protect setup time	$t_{SU.WP}$	0	—	—	ns	
Write cycle time	$t_{WC}$	—	—	5.0	ms	2

Notes: 1. This parameter is sampled and not 100% tested.

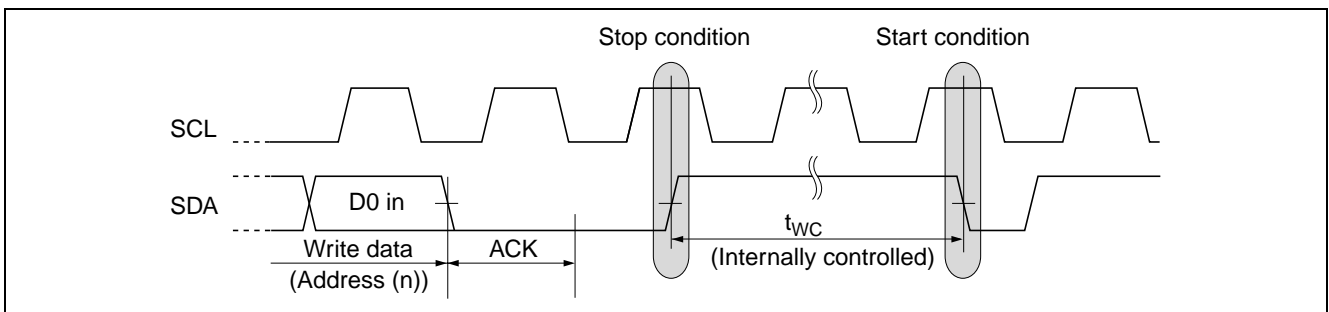
2.  $t_{WC}$  is the time from a stop condition to the end of internally controlled write cycle.

## Timing Waveforms

### Bus Timing



### Write Cycle Timing



## Pin Function

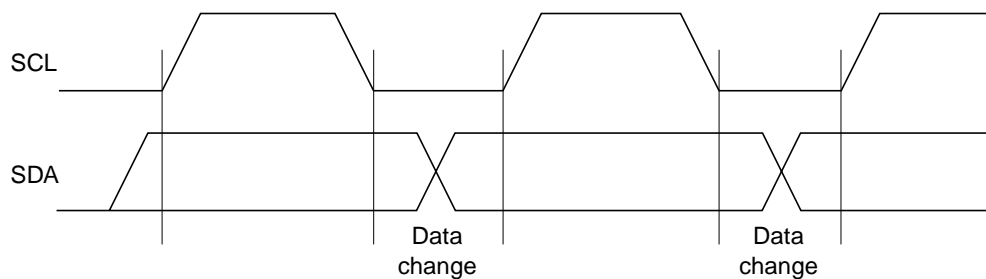
### Serial Clock (SCL)

The SCL pin is used to control serial input/output data timing. The SCL input is used to positive edge clock data into EEPROM device and negative edge clock data out of each device. Maximum clock rate is 1 MHz.

### Serial Input/Output Data (SDA)

The SDA pin is bidirectional for serial data transfer. The SDA pin needs to be pulled up by resistor as that pin is open-drain driven structure. Use proper resistor value for your system by considering  $V_{OL}$ ,  $I_{OL}$  and the SDA pin capacitance. Except for a start condition and a stop condition, which will be discussed later, the SDA transition needs to be completed during the SCL low period.

### Data Validity (SDA data change timing waveform)



Note: High-to-low and low-to-high change of SDA should be done during the SCL low period.



**Device Address (A1, A2)**

Up to four devices can be addressed on the same bus by setting the levels on these pins to different combinations. The levels on these pins are compared with the device address code which are inputted through the SDA pin. These device is selected if the compare is successfully done. These pins are internally pulled down to  $V_{SS}$ . The device read these pins as low if unconnected.

**Pin Connections for A1, A2**

Memory size	Max connect number	Pin connection		Note
		A2	A1	
1M bit	4	$V_{CC}/V_{SS}$	$V_{CC}/V_{SS}$	1

Note: 1. " $V_{CC}/V_{SS}$ " means that device address pin should be connected to  $V_{CC}$  or  $V_{SS}$ . The A1 and A2 are read as  $V_{SS}$ , if left unconnected.

**Write Protect (WP)**

When the Write Protect pin (WP) is high, the write protection feature is enabled and operates as shown in the following table. When the WP is low, write operation for all memory arrays are allowed. The read operation is always activated irrespective of the WP pin status. When left unconnected, the WP input is read as  $V_{IL}$  because the WP pin is internally pulled down to  $V_{SS}$ .

**Write Protect Area**

WP pin status	Write protect area
$V_{IH}$	Full (1M bit)
$V_{IL}$	Normal read/write operation

## Functional Description

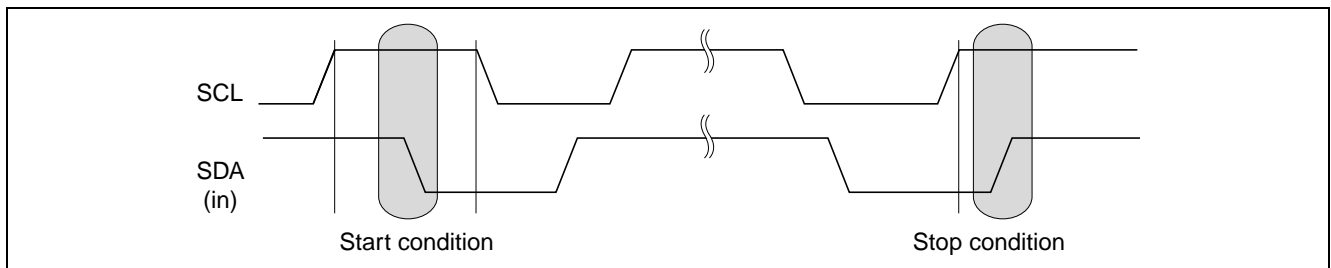
### Start Condition

A high-to-low transition of the SDA with the SCL high is needed in order to start read, write operation. (See start condition and stop condition)

### Stop Condition

A low-to-high transition of the SDA with the SCL high is a stop condition. The stand-by operation starts after a read sequence by a stop condition. In the case of write operation, a stop condition terminates the write data inputs and place the device in a internally-timed write cycle to the memories. After the internally-timed write cycle which is specified as  $t_{WC}$ , the device enters a standby mode. (See write cycle timing)

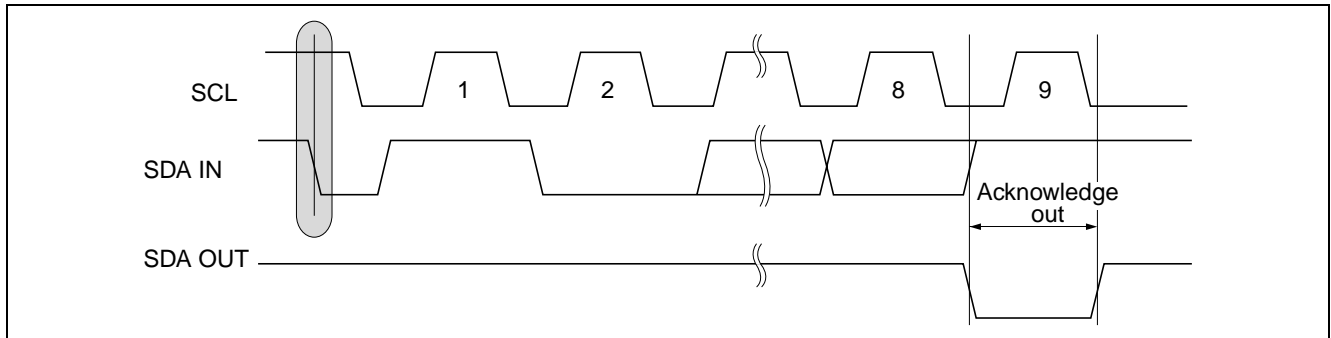
### Start Condition and Stop Condition



## Acknowledge

All addresses and data words are serially transmitted to and from in 8-bit words. The receiver sends a zero to acknowledge that it has received each word. This happens during ninth clock cycle. The transmitter keeps bus open to receive acknowledgment from the receiver at the ninth clock. In the write operation, EEPROM sends a zero to acknowledge after receiving every 8-bit words. In the read operation, EEPROM sends a zero to acknowledge after receiving the device address word. After sending read data, the EEPROM waits acknowledgment by keeping bus open. If the EEPROM receives zero as an acknowledge, it sends read data of next address. If the EEPROM receives acknowledgment "1" (no acknowledgment) and a following stop condition, it stops the read operation and enters a stand-by mode. If the EEPROM receives neither acknowledgment "0" nor a stop condition, the EEPROM keeps bus open without sending read data.

## Acknowledge Timing Waveform



## Device Addressing

The EEPROM device requires an 8-bit device address word following a start condition to enable the chip for a read or a write operation. The device address word consists of 4-bit device code, 3-bit device address code and 1-bit read/write(R/W) code. The most significant 4-bit of the device address word are used to distinguish device type and this EEPROM uses “1010” fixed code. The device address word is followed by the 2-bit device address code. The device address code selects one device out of all devices which are connected to the bus. This means that the device is selected if the inputted 3-bit device address code is equal to the corresponding hard-wired A2 to A1 pin status. The third bit of the device address code is used as memory address. The eighth bit of the device address word is the read/write(R/W) bit. A write operation is initiated if this bit is low and a read operation is initiated if this bit is high. Upon a compare of the device address word, the EEPROM enters the read or write operation after outputting the zero as an acknowledge. The EEPROM turns to a stand-by state if the device code is not “1010” or device address code doesn’t coincide with status of the correspond hard-wired device address pins A1 to A2.

## Device Address Word

	Device address word (8-bit)							
	Device code (fixed)				Device address code			R/W code*1
1M	1	0	1	0	A2	A1	a16	R/W

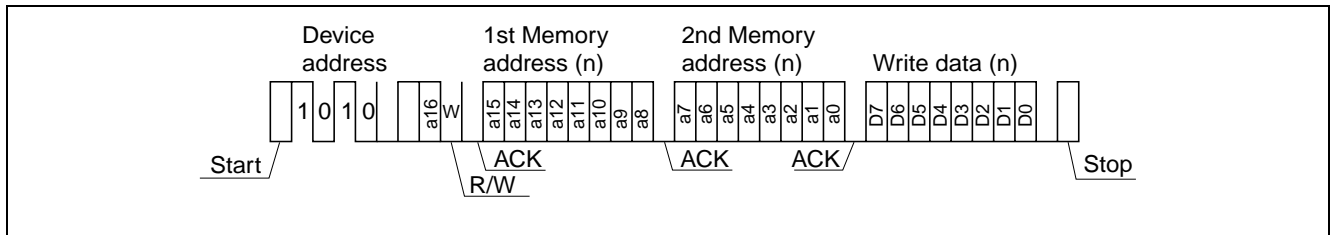
Notes: 1. R/W=“1” is read and R/W = “0” is write.

## Write Operations

### Byte Write:

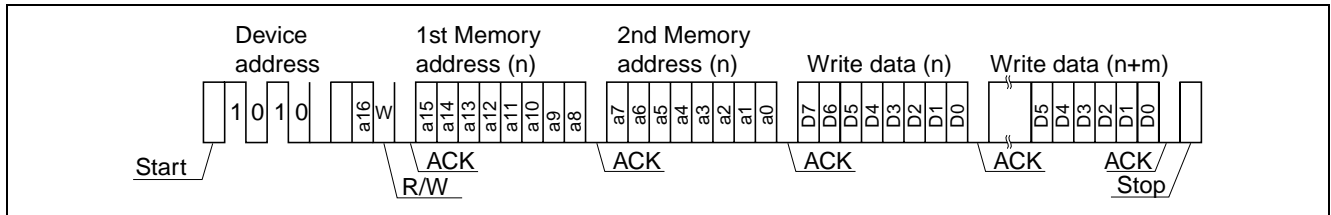
A write operation requires an 8-bit device address word with R/W = "0". Then the EEPROM sends acknowledgment "0" at the ninth clock cycle. After these, the EEPROM receives 2 sequence 8-bit memory address words. Upon receipt of this memory address, the EEPROM outputs acknowledgment "0" and receives a following 8-bit write data. After receipt of write data, the EEPROM outputs acknowledgment "0". If the EEPROM receives a stop condition, the EEPROM enters an internally-timed write cycle and terminates receipt of SCL, SDA inputs until completion of the write cycle. The EEPROM returns to a standby mode after completion of the write cycle.

### Byte Write Operation



**Page Write:**

The EEPROM is capable of the page write operation which allows any number of bytes up to 256 bytes to be written in a single write cycle. The page write is the same sequence as the byte write except for inputting the more write data. The page write is initiated by a start condition, device address word, memory address(n) and write data (Dn) with every ninth bit acknowledgment. The EEPROM enters the page write operation if the EEPROM receives more write data (Dn+1) instead of receiving a stop condition. The a0 to a7 address bits are automatically incremented upon receiving write data (Dn+1). The EEPROM can continue to receive write data up to 256 bytes. If the a0 to a7 address bits reaches the last address of the page, the a0 to a7 address bits will roll over to the first address of the same page and previous write data will be overwritten. Upon receiving a stop condition, the EEPROM stops receiving write data and enters internally-timed write cycle.

**Page Write Operation**

**Acknowledge Polling:**

Acknowledge polling feature is used to show if the EEPROM is in a internally-timed write cycle or not. This feature is initiated by the stop condition after inputting write data. This requires the 8-bit device address word following the start condition during a internally-timed write cycle. Acknowledge polling will operate when the R/W code = "0". Acknowledgment "1" (no acknowledgment) shows the EEPROM is in a internally-timed write cycle and acknowledgment "0" shows that the internally-timed write cycle has completed. See Write Cycle Polling using ACK.

**Write Cycle Polling Using ACK**

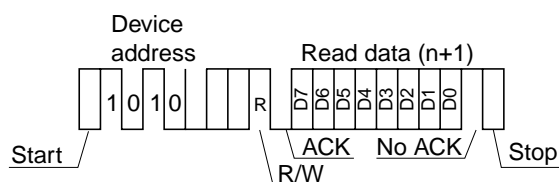
## Read Operation

There are three read operations: current address read, random read, and sequential read. Read operations are initiated the same way as write operations with the exception of R/W = "1".

### Current Address Read:

The internal address counter maintains the last address accessed during the last read or write operation, with incremented by one. Current address read accesses the address kept by the internal address counter. After receiving a start condition and the device address word (R/W is "1"), the EEPROM outputs the 8-bit current address data from the most significant bit following acknowledgment "0". If the EEPROM receives acknowledgment "1" (no acknowledgment) and a following stop condition, the EEPROM stops the read operation and is turned to a standby state. In case the EEPROM has accessed the last address of the last page at previous read operation, the current address will roll over and returns to zero address. In case the EEPROM has accessed the last address of the page at previous write operation, the current address will roll over within page addressing and returns to the first address in the same page. The current address is valid while power is on. The current address after power on will be indefinite. The random read operation described below is necessary to define the memory address.

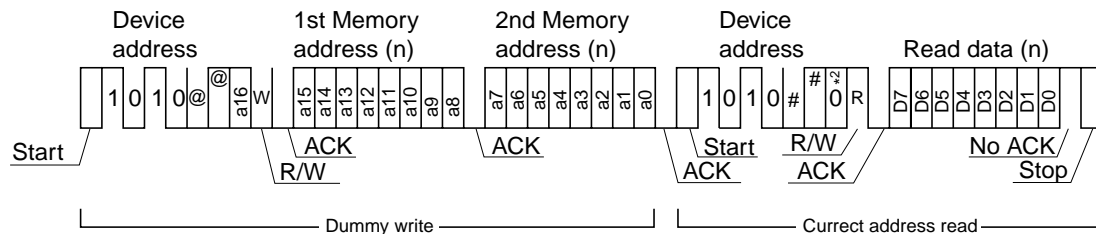
### Current Address Read Operation





**Random Read:**

This is a read operation with defined read address. A random read requires a dummy write to set read address. The EEPROM receives a start condition, device address word (R/W=0) and memory address  $2 \times 8$ -bit sequentially. The EEPROM outputs acknowledgment "0" after receiving memory address then enters a current address read with receiving a start condition. The EEPROM outputs the read data of the address which was defined in the dummy write operation. After receiving acknowledgment "1" (no acknowledgment) and a following stop condition, the EEPROM stops the random read operation and returns to a standby state.

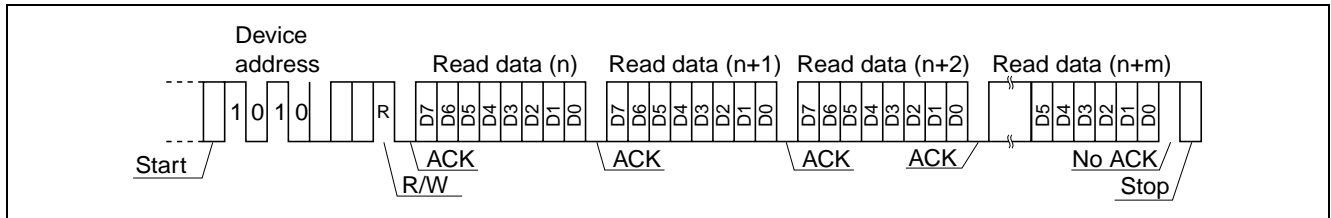
**Random Read Operation**

- Notes: 1. 2nd device address code (#) should be same as 1st (@).  
 2. Don't care bit.

### Sequential Read:

Sequential reads are initiated by either a current address read or a random read. If the EEPROM receives acknowledgment “0” after 8-bit read data, the read address is incremented and the next 8-bit read data are coming out. This operation can be continued as long as the EEPROM receives acknowledgment “0”. The address will roll over and returns address zero if it reaches the last address of the last page. The sequential read can be continued after roll over. The sequential read is terminated if the EEPROM receives acknowledgment “1” (no acknowledgment) and a following stop condition.

### Sequential Read Operation



## Notes

### Data Protection at $V_{CC}$ On/Off

When  $V_{CC}$  is turned on or off, noise on the SCL and SDA inputs generated by external circuits (CPU, etc) may act as a trigger and turn the EEPROM to unintentional program mode. To prevent this unintentional programming, this EEPROM has a power on reset function. Be careful of the notices described below in order for the power on reset function to operate correctly.

- SCL and SDA should be fixed to  $V_{CC}$  or  $V_{SS}$  during  $V_{CC}$  on/off. Low to high or high to low transition during  $V_{CC}$  on/off may cause the trigger for the unintentional programming.
- $V_{CC}$  should be turned off after the EEPROM is placed in a standby state.
- $V_{CC}$  turn on speed ( $t_r$ ) should be longer than 10  $\mu s$  ( $t_r > 10 \mu s$ ).

### Write/Erase Endurance and Data Retention Time

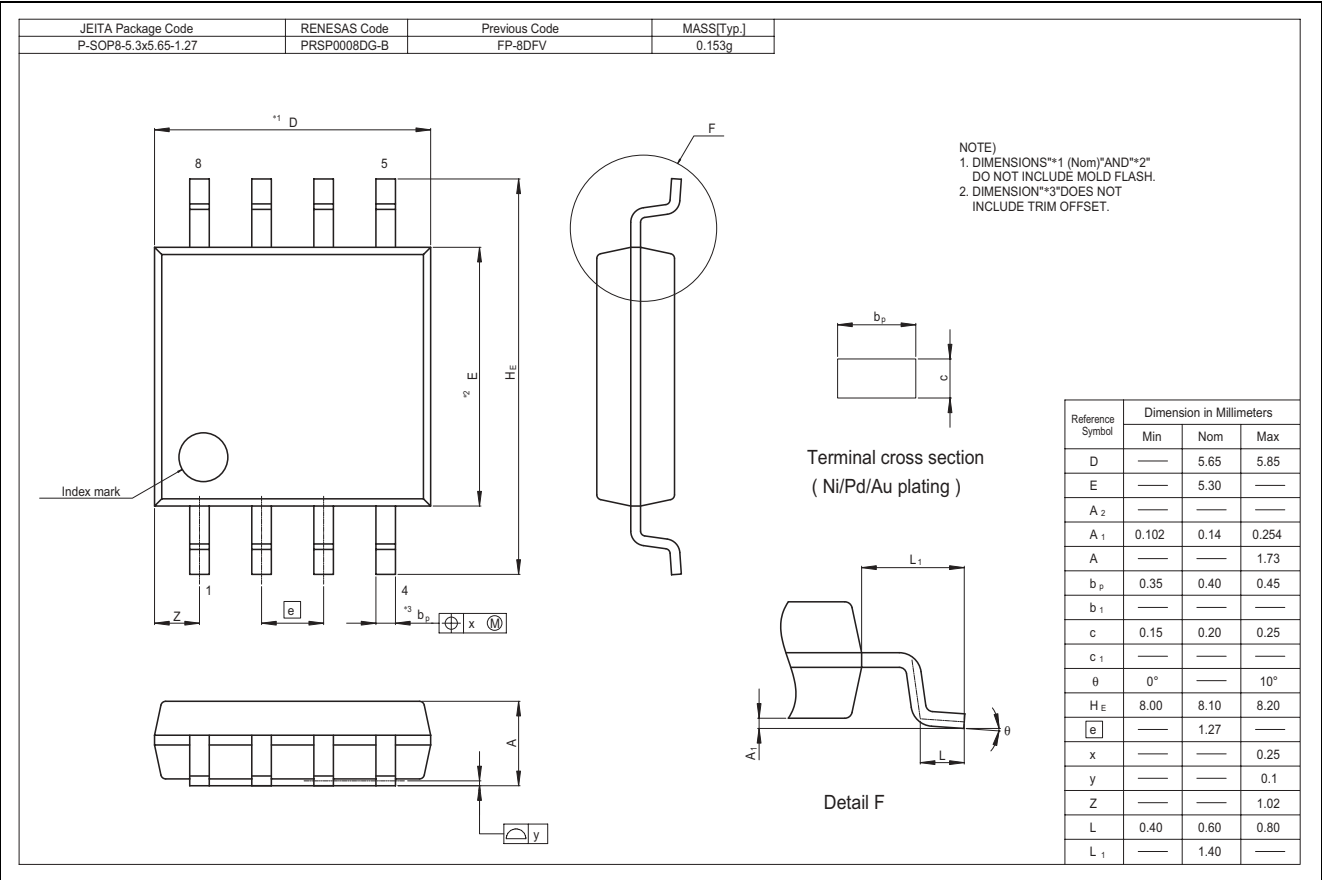
The endurance for programming is  $10^5$  cycles (1% cumulative failure rate). The data retention time is more than 10 years.

### Noise Suppression Time

This EEPROM have a noise suppression function at SCL and SDA inputs, that cut noise of width less than 50 ns. Be careful not to allow noise of width more than 50 ns.

Package Dimensions

HN58W241000FPIE (PRSP0008DG-B / Previous Code: FP-8DFV)



<b>Revision History</b>	<b>HN58W241000I Data Sheet</b>
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Rev.	Date	Contents of Modification	
		Page	Description
0.0	Jul. 10, 2002	—	Initial issue
1.00	Nov.12, 2003	— — 2 19	Change format issued by Renesas Technology Corp. Deletion of Preliminary Ordering Information Addition of HN58W241000FPIE Package Dimensions FP-8DF to FP-8DF, FP-8DFV
2.00	Dec.13.2004	2 19	Ordering Information Deletion of HN58W241000FPI Package Dimensions Deletion of FP-8DF
3.00	Jul.12.2005	1 4 5 18	Ordering Information Addition of Renesas package codes AC Characteristics Addition of $t_{HD.WP}$ Addition of $t_{SU.WP}$ Timing Waveforms Addition of WP Package Dimensions Addition of Renesas package codes Changed to Renesas formats

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Tel: <82> 2-796-3115, Fax: <82> 2-796-2145

#### **Renesas Technology Malaysia Sdn. Bhd.**

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia  
Tel: <603> 7955-9390, Fax: <603> 7955-9510